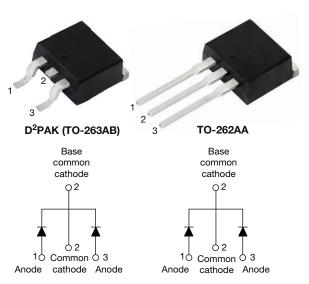
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Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 15 A



VS-32CTQ...S-M3

VS-32CTQ ... -1-M3

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _R	25 V, 30 V				
V _F at I _F	0.40 V				
I _{RM} max.	97 mA at 125°C				
T _J max.	150 °C				
E _{AS}	13 mJ				
Package	D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation



HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Rectangular waveform	30	A					
V _{RRM}		25, 30	V					
I _{FSM}	t _p = 5 μs sine	900	А					
V _F	15 A _{pk} , T _J = 125 °C	0.40	V					
Тј	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-32CTQ025S-M3 VS-32CTQ025-1-M3	VS-32CTQ030S-M3 VS-32CTQ030-1-M3	UNITS		
Maximum DC reverse voltage	V _R	25	30	V		
Maximum working peak reverse voltage	V _{RWM}	25	50	v		



ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	$I_{F(AV)}$ 50 % duty cycle at T _C = 115 °C, rectangular waveform					
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	900	A		
surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		13	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum forward voltage drop See fig. 1		15 A	T 05 %C	0.49	v		
	V _{FM} ⁽¹⁾	30 A	T _J = 25 °C	0.58			
	VFM ()	15 A	T 105 %O	0.40			
		30 A	T _J = 125 °C	0.53			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Reted V	1.75	mA		
See fig. 2	IRM ("	T _J = 125 °C	$V_R = Rated V_R$	97			
Threshold voltage	V _{F(TO)}	T T maximum		0.233	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		9.09	mΩ		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C			pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body 8.0 nH			nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ					

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torgue	minimum			6 (5)	kgf ⋅ cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
			Case style D ² PAK (TO-263AB)	32CTQ025S			
Marking device			Case sigle D-PAR (TO-203AB)	32CT0	2030S		
			Case style TO 2624A	32CTC	TQ025-1		
			Case style TO-262AA	32CTC	2030-1		



VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

Vishay Semiconductors

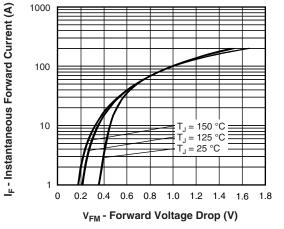
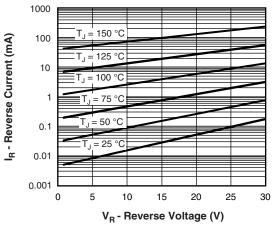
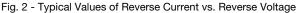


Fig. 1 - Maximum Forward Voltage Drop Characteristics





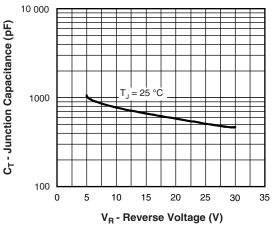


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

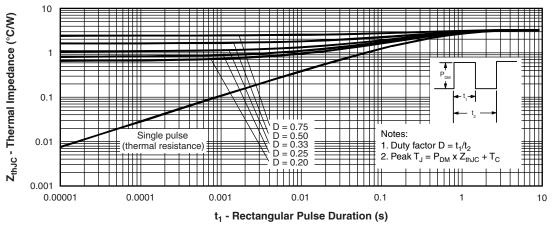
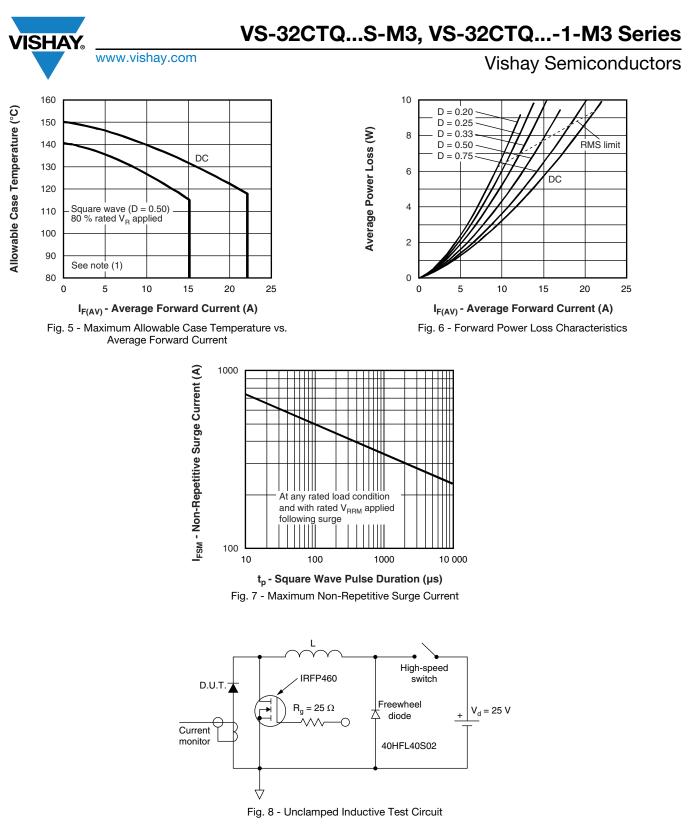


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at V_{R1} = 80 % rated V_R

Revision: 27-Oct-17

4

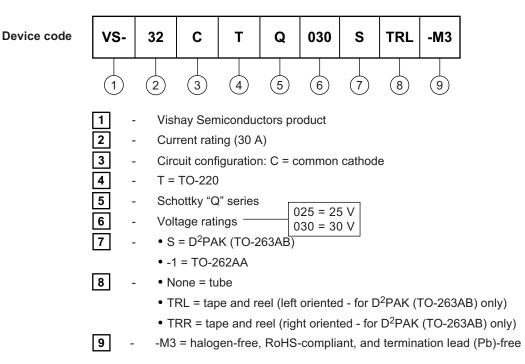
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ORDERING INFORMATION TABLE

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ORDERING INFORMATION						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-32CTQ025S-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ025STRR-M3	800	800	13" diameter reel			
VS-32CTQ025STRL-M3	800	800	13" diameter reel			
VS-32CTQ025-1-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ030S-M3	50	1000	Antistatic plastic tubes			
VS-32CTQ030STRR-M3	800	800	13" diameter reel			
VS-32CTQ030STRL-M3	800	800	13" diameter reel			
VS-32CTQ030-1-M3	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Deut menting information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

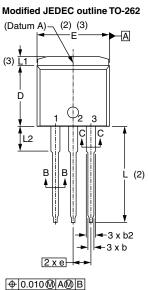


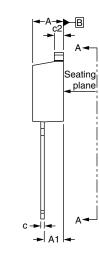
Outline Dimensions

Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches

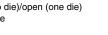


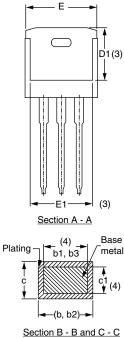


Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

CVMDOI	MILLIM	ETERS	INC	NOTES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

Revision: 04-Oct-10

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

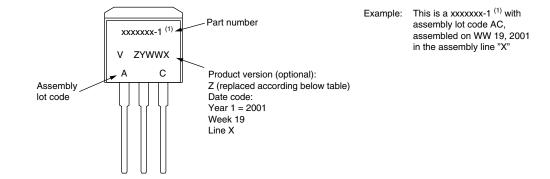
(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Document Number: 95419 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



TO-262



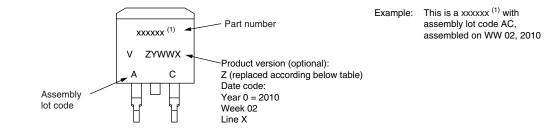
Note

⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z) PRODUCT DEFINITION			
A Termination lead (Pb)-free			
B Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free		
Ν	Halogen-free, RoHS-compliant and totally lead (Pb)-free		
G	Green		



D²PAK



Note

⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
А	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green



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